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FORM PTO-1449 (Modified) LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT					ATTY. DOCKET	SERIA	SERIAL NO.: 09/838,892		
					APPLICANT: J. O. Chu et al.				
					FILING DATE: April 20, 2001	GROU	GROUP: 2811		
REFEREN	NCE	DESIGNATION	U.S.	PATI	ENT DOCUMENTS	6			
EXAMINER INITIALS		DOCUMENT NUMBER	DATE	NAME		CLASS	SUBCLASS	FILING DATE (IF APPRO.)	
CM	AA	5,906,680	5/25/1999		Meyerson	117	88		
	AB								
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			FOREI	GN PA	ATENT DOCUME	NTS			
		DOCUMENT	7.4		COUNTRY	CLASS	SUBCLASS	TRANSLATION	
		NUMBER	DATE					YES	NO
	AD								
	ΑE								
	AF								
		OTHER A	ART (Includin	g Aut	hor, Title, Date, Pe	rtinent Pa	ages, etc.)		
45	AG	E. Kasper et al., "Growth of 100 GHz SiGe-Heterobipolar Transistor (HBT) Structures," Jpn J Appl Phys, Vol. 33 Pt. 1, No. 4B, April 1994, pp. 2415-2418.							
ψ	АН	H.J. Osten et al., in the paper entitled "Carbon Doped SiGe Heterojunction Bipolar Transistors for High Frequency Applications," IEEE BCTM 7.1, 1999, pp. 109-116.							

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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